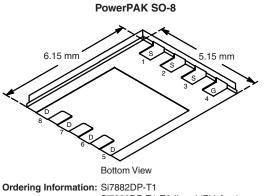


Vishay Siliconix

N-Channel Reduced Q_q, Fast Switching MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
12	0.0055 at V_{GS} = 4.5 V	22		
	0.008 at V _{GS} = 2.5 V	18		

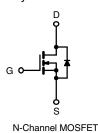


FEATURES

- Halogen-free available
- TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile
- PWM Optimized for High Efficiency
- 100 % R_g Tested

APPLICATIONS

- Point-of-Load Synchronous Rectifier
- 5 V or 3.3 V BUS Step Down
- Q_a Optimized for 500 kHz Operation
- Synchronous Buck, Shoot-Thru Resistant



Bottom View	
Ordering Information: Si7882DP-T1 Si7882DP-T1-E3 (Lead (Pb)-free Si7882DP-T1-GE3 (Lead (Pb)-fr	
ABSOLUTE MAXIMUM RATINGS	$T_A = 25 ^{\circ}C$, unless otherwise noted

Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	12		V
Gate-Source Voltage		V _{GS}	± 8		
Continuous Drain Current (T _{.1} = 150 °C) ^a	T _A = 25 °C	– I _D	22	13	
Continuous Drain Current $(T_j = 150 \text{ C})$	T _A = 70 °C		18	11	
Pulsed Drain Current		I _{DM}	50		А
Continuous Source Current (Diode Conduction) ^a		۱ _S	4.1	1.6	
Single Pulse Avalanche Energy	L = 0.1 mH	I _{AS}	12		
Avalanche Energy	L = 0.1 mm	E _{AS}	7.2		mJ
Mauinum Davier Disainational	T _A = 25 °C	$T_A = 25 \degree C$ P_D		1.9	W
Maximum Power Dissipation ^a	T _A = 70 °C	' D	3.2	1.2	vv
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b, c}			260		

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit	
Maximum lunction to Ambient (MOCEET) ^a	t ≤ 10 s	– R _{thJA}	20	25		
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		55	65	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	2.0	2.6		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

* Pb containing terminations are not RoHS compliant, exemptions may apply.



RoHS COMPLIANT

Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	0.6		1.4	V	
Gate-Body Leakage	I _{GSS}				± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}$			1		
	IDSS	V_{DS} = 12 V, V_{GS} = 0 V, T_{J} = 70 °C			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, $V_{GS} = 4.5$ V	40			А	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 17 \text{ A}$		0.0045	0.0055	Ω	
		$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 14 \text{ A}$		0.0065	0.008		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 6 V, I_{D} = 17 A$		80		S	
Diode Forward Voltage ^a	V _{SD}	$I_{S} = 2.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.70	1.1	V	
Dynamic ^b							
Total Gate Charge	Qg			21	30		
Gate-Source Charge	Q _{gs}	$V_{DS} = 6 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 17 \text{ A}$		4.6		nC	
Gate-Drain Charge	Q _{gd}			3.5			
Gate Resistance	R _g		0.8		3.5	Ω	
Turn-On Delay Time	t _{d(on)}			28	42		
Rise Time	t _r	V_{DD} = 6 V, R_L = 6 Ω		32	48	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong \text{1}$ A, V_GEN = 4.5 V, R_G = 6 Ω		82	123		
Fall Time	t _f			35	53		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.7 A, di/dt = 100 A/μs		60	90		

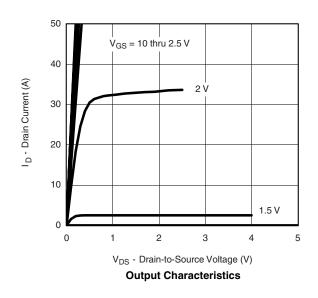
Notes:

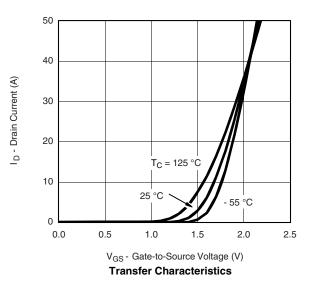
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

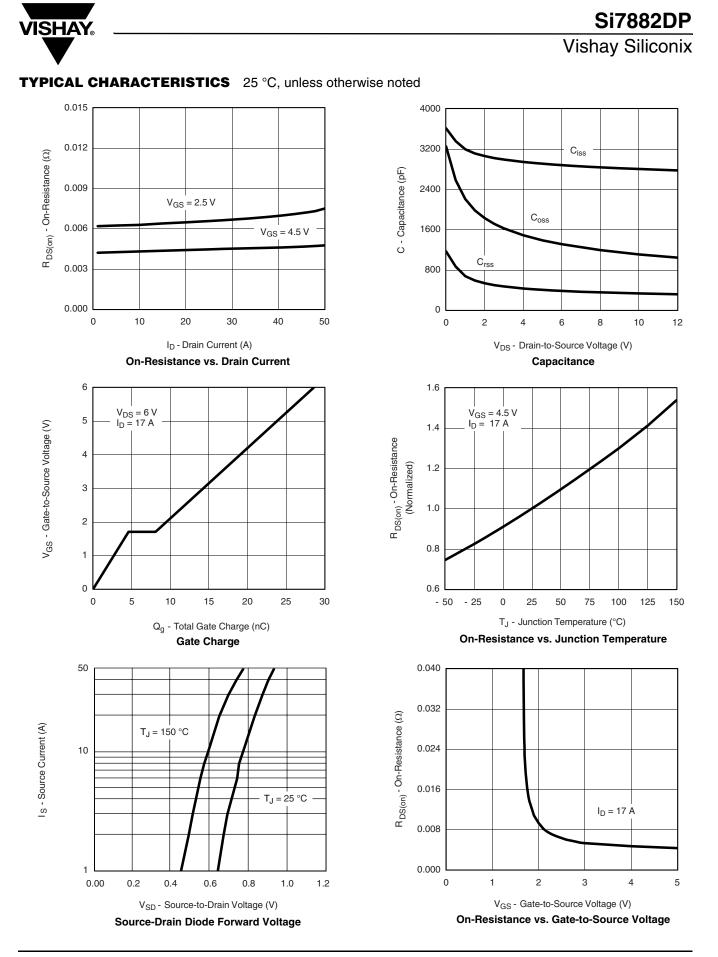
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



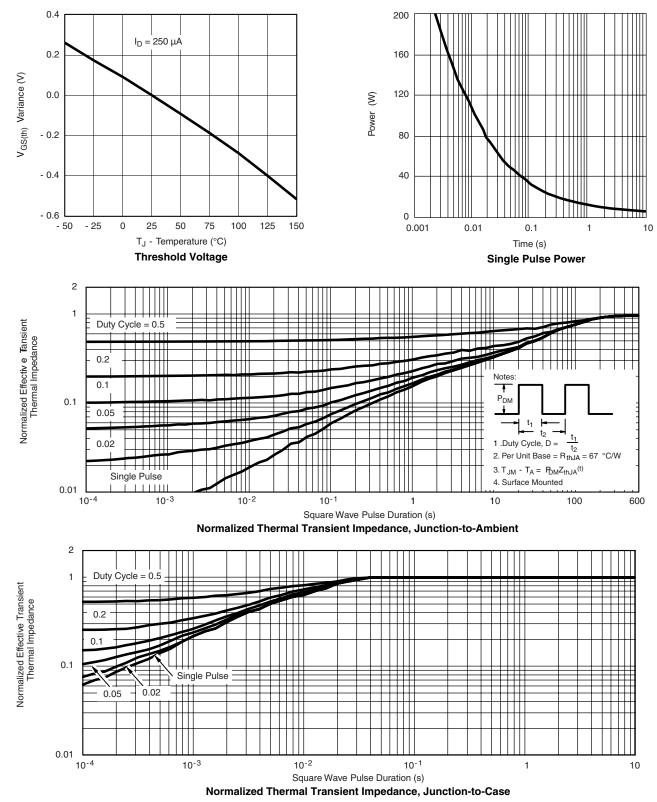




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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71858.





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